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View Online at https://aerobasegroup.com/nsn/5961-01-024-3741
Inclosure Material:
Metal
Overall Length:
Between 0.250 inches and 0.340 inches
Terminal Length:
0.360 inches
Overall Diameter:
0.500 inches
Mounting Facility Quantity:
3
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-66
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Terminal Circle Diameter:
Between 0.190 inches and 0.210 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
4.00 amperes source cutoff current
Power Rating Per Characteristic:
20.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
82577-928847 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
1 case and 2 uninsulated wire lead
Shelf Life:
N/a

Unit Of Measure:

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No

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